

AMENDMENTS TO THE CLAIMS

The following listing of claims will replace all prior versions and listings of claims in the application.

LISTING OF CLAIMS

1. (Currently Amended) A temperature and process independent analog integrated circuit comprising:

an analog function core responsive to a first differential input signal and a second differential input signal, [and] the analog function core having a first output terminal and a second output [terminals] terminal;

a first loading device having

_____ a first terminal responsive to the first output terminal,

_____ a second terminal responsive to a common mode voltage, and

_____ a first control terminal;

a second loading device having

_____ a third terminal responsive to the second output terminal,

_____ a fourth terminal responsive to the common mode voltage, and

_____ a second control terminal; and

_____ a compensation circuit in communication with [said] the first control terminal and the second control [terminals] terminal,

_____ wherein [said] the compensation circuit comprises:

_____ a first MOS transistor having

_____ a first source in communication with the common mode voltage,

_____ a first drain, and

_____ a first gate in communication with the first control terminal and the second control [terminals] terminal; and

_____ a first differential amplifier having

_____ a first input in communication with a first bias voltage source,

_____ a second input in communication with the first drain, and

_____ an output in communication with the first gate, [and] the first control terminal, and the second control [terminals] terminal.

2. (Currently Amended) The temperature and process independent analog integrated circuit of claim 1, wherein [said] the analog function core is selected from the group consisting

of multipliers, adaptive filters, function generators, modulators, and neural networks.

3. (Currently Amended) The temperature and process independent analog integrated circuit of claim 1, wherein the analog [integrated] function core [circuit] is a multiplier circuit comprising:

a first current source;

a second current source;

a first pair of first and second MOS transistors arranged in parallel, the first pair of first and second MOS transistors having

_____a gate of the first MOS transistor in communication with a first terminal of the first differential input signal,

_____a gate of the second MOS transistor in communication with a second terminal of the first differential input signal,

_____commonly connected first drains in communication with the first current source, and

_____commonly connected first sources;

a second pair of third and fourth MOS transistors arranged in parallel, the second pair of third and fourth MOS transistors having

_____a gate of the third MOS transistor in communication with a first terminal of the second differential input signal,

_____ a gate of the fourth MOS transistor in communication with a second terminal of the second differential input signal, _____ commonly connected second drains in communication with the second current source, and _____ commonly connected second sources;

a third current source in communication with the commonly connected first sources to form the first output terminal; and

a fourth current source in communication with the commonly connected second sources to form the second output terminal.

4. (Currently Amended) The temperature and process independent analog integrated circuit of claim 1, wherein the first and second loading devices comprise MOS transistors.

5. (Currently Amended) The temperature and process independent analog integrated circuit of claim 1, wherein said compensation circuit further comprises:

a second MOS transistor having

_____ a second gate,

_____ a second drain in communication with the first drain, and

_____ a second source;

a third MOS transistor in communication with a second bias voltage source, the third MOS transistor having

_____a third source in communication with a reference point, and

_____a third drain in communication with the second source; and

a second differential amplifier having

_____a second input in communication with the third drain and the second source,

_____a third input in communication with a third bias voltage source, and

_____an output in communication with the second gate.

6. (Currently Amended) The temperature and process independent analog integrated circuit of claim 5, wherein the first MOS transistor and the first and second loading devices are of a first conductivity type, and the second and third MOS transistors are of a second conductivity type.

7. (Currently Amended) The temperature and process independent analog integrated circuit of claim 1, further comprising a biasing circuit to provide the common mode voltage to the first and second loading devices.

8. (Currently Amended) The temperature and process independent analog integrated circuit of claim 5, further

comprising a biasing circuit, wherein the biasing circuit
[comprising] comprises:

a common mode voltage source to provide the common mode voltage that is referenced to a semiconductor bandgap voltage;

a first bias voltage source to provide a first bias voltage to the first MOS transistor, the first bias voltage being [that is] referenced to the semiconductor bandgap voltage;

a second bias voltage source to provide the second bias voltage to the second MOS transistor, the second bias voltage being [that is] referenced to [a] the semiconductor bandgap voltage; and

a third bias voltage source to provide the third bias voltage to the third MOS transistor, the third bias voltage being [that is] referenced to [a] the semiconductor bandgap voltage.

9. (Currently Amended) The temperature and process independent analog integrated circuit of claim 7, wherein the common mode voltage is substantially proportional to a semiconductor bandgap voltage.

10. (Currently Amended) A temperature and process independent analog multiplier circuit comprising:

a multiplier core responsive to a first differential input signal and a second differential input signal, [and] the multiplier core having a first output terminal and a second output [terminals] terminal;

a first loading device having
_____a first terminal responsive to the first output terminal,
_____a second terminal responsive to a common mode voltage,
and
_____a first control terminal;

a second loading device having
_____a third terminal responsive to the second output terminal,
_____a fourth terminal responsive to the common mode voltage, and
_____a second control terminal; and

a compensation circuit in communication with [said] the first control terminal and the second control [terminals] terminal,

_____ wherein [said] the compensation circuit comprises:

_____ a first MOS transistor having
_____a first source in communication with the common mode voltage,
_____a first drain, and

_____ a first gate in communication with the first
control terminal and the second control [terminals] terminal;
and
_____ a first differential amplifier having
_____ a first input in communication with a first bias
voltage source,
_____ a second input in communication with the first
drain, and
_____ an output in communication with the first gate,
and the first control terminal, and the second control
[terminals] terminal.

11. (Currently Amended) The temperature and process
independent analog multiplier circuit of claim 10, wherein the
multiplier core comprises:

a first current source;
a second current source;
a first pair of first and second MOS transistors arranged
in parallel, the first pair of first and second MOS transistors
having
_____ a gate of the first MOS transistor in communication
with a first terminal of the first differential input signal,
_____ a gate of the second MOS transistor in communication
with a second terminal of the first differential input signal,

_____commonly connected first drains in communication with the first current source, and

_____commonly connected first sources;

a second pair of third and fourth MOS transistors arranged in parallel, the second pair of third and fourth MOS transistors having

_____a gate of the third MOS transistor in communication with a first terminal of the second differential input signal,

_____a gate of the fourth MOS transistor in communication with a second terminal of the second differential input signal,

_____commonly connected second drains in communication with the second current source, and

_____commonly connected second sources;

a third current source in communication with the commonly connected first sources to form the first output terminal; and

a fourth current source in communication with the commonly connected second sources to form the second output terminal.

12. (Currently Amended) The temperature and process independent analog multiplier circuit of claim 10, wherein the first and second loading devices comprises MOS transistors.

13. (Currently Amended) The temperature and process independent analog multiplier circuit of claim 10, wherein [said] the compensation circuit further comprises:

a second MOS transistor having
_____ a second gate,
_____ a second drain in communication with the first drain,
and
_____ a second source;
a third MOS transistor in communication with a second bias voltage source, the third MOS transistor having
_____ a third source in communication with a reference point, and
_____ a third drain in communication with the second source;
and
a second differential amplifier having
_____ a second input in communication with the third drain and the second source,
_____ a third input in communication with a third bias voltage source, and
_____ an output in communication with the second gate.

14. (Currently Amended) The temperature and process independent analog multiplier circuit of claim 13, wherein the first MOS transistor and the first and second loading devices

are of a first conductivity type, and the second and third MOS transistors are of a second conductivity type.

15. (Currently Amended) The temperature and process independent analog multiplier circuit of claim 11, further comprising a biasing circuit to provide the common mode voltage to the first and second loading devices.

16. (Currently Amended) The temperature and process independent analog multiplier circuit of claim 13, further comprising a biasing circuit, wherein the biasing circuit [comprising] comprises:

a common mode voltage source to provide the common mode voltage that is referenced to a semiconductor bandgap voltage;

a first bias voltage source to provide a first bias voltage to the first MOS transistor, the first bias voltage being [that is] referenced to the semiconductor bandgap voltage;

a second bias voltage source to provide a second bias voltage to the second MOS transistor, the second bias voltage being [that is] referenced to [a] the semiconductor bandgap voltage; and

a third bias voltage source to provide a third bias voltage to the third MOS transistor, the third bias voltage being [that is] referenced to [a] the semiconductor bandgap voltage.

17. (Currently Amended) The temperature and process independent analog multiplier circuit of claim 15, wherein the common mode voltage is substantially proportional to a semiconductor bandgap voltage.

18. (Currently Amended) A temperature and process compensation circuit in communication with control terminals of an active load of an analog integrated circuit to counteract changes in an output level of [said] the analog integrated circuit due to temperature and manufacturing process, [said] the temperature and process compensation circuit comprising:

a first MOS transistor having

_____ a first source in communication with a common mode voltage,

_____ a first drain, and

_____ a first gate in communication with the control terminals;

a first differential amplifier having

_____ a first input in communication with a first bias voltage,

_____ a second input in communication with the first drain, and

_____ an output in communication with the control terminals;

a second MOS transistor having
_____ a second gate,
_____ a second drain [in communication with] connected to
the first drain, and
_____ a second source;
a third MOS transistor having
_____ a third gate in communication with a second bias
voltage,
_____ a third source in communication with a reference
point, and
_____ a third drain in communication with the second source;
and
a second differential amplifier having
_____ a second input connected to the third drain and the
second source,
_____ a third input in communication with a third bias
voltage, and
_____ an output in communication with the second gate.

19. (Currently Amended) The temperature and process compensation circuit of claim 18, wherein the first MOS transistor is of [the] a first conductivity type, and the second and third MOS transistors are of [the] a second conductivity type.

20. (Currently Amended) The temperature and process compensation circuit of claim 18, further comprising a biasing circuit to provide the common mode voltage and to provide the first bias voltage, second bias voltage, and third bias voltage to [said] the temperature and process compensation circuit.

21. (Currently Amended) The temperature and process compensation circuit of claim 20, further comprising a biasing circuit, wherein the biasing circuit [comprising] comprises:

a common mode voltage source to provide the common mode voltage that is referenced to a semiconductor bandgap voltage;

a first bias voltage source to provide [a] the first bias voltage to the first [MOS transistor] differential amplifier, the first bias voltage being [that is] referenced to the semiconductor bandgap voltage;

a second bias voltage source to provide [a] the second bias voltage to the [second] third MOS transistor, the second bias voltage being [that is] referenced to [a] the semiconductor bandgap voltage; and

a third bias voltage source to provide [a] the third bias voltage to the [third MOS transistor] second differential amplifier, the third bias voltage being [that is] referenced to [a] the semiconductor bandgap voltage.

22. (Currently Amended) A temperature and process independent analog integrated circuit comprising:

analog integrated function means for providing first and second output signals responsive to a first differential input signal pair and a second differential input signal pair;

first loading means for providing an output voltage in response to the first output signal, a common mode voltage signal, and a compensation control signal;

second loading means for providing an output voltage in response to the second output signal, the common mode voltage signal, and the compensation control signal; and

compensation [circuit] means for generating the compensation control signal to compensate for changes due to temperature and manufacturing variations.

23. (Currently Amended) The temperature and process independent analog integrated circuit of claim 22, wherein [said] the analog integrated function means is selected from the group consisting of multipliers, adaptive filters, function generators, modulators, and neural networks.

24. (Currently Amended) The temperature and process independent analog integrated circuit of claim 22, wherein the

analog integrated function means is a multiplier circuit comprising:

first current means for supplying a first current;

_____second current means for supplying a second current;

a first pair of first and second MOS transistors arranged in parallel, the first pair of first and second MOS transistors having

_____a gate of the first MOS transistor in communication with a first terminal of the first differential input signal pair,

_____a gate of the second MOS transistor in communication with a second terminal of the first differential input signal pair,

_____commonly connected first drains responsive to the first current, and

_____commonly connected first sources;

a second pair of third and fourth MOS transistors arranged in parallel, the second pair of third and fourth MOS transistors having

_____a gate of the third MOS transistor in communication with a first terminal of the second differential input signal pair,

_____a gate of the fourth MOS transistor in communication with a second terminal of the second differential input signal pair,

_____commonly connected second drains responsive to the second current, and

_____commonly connected second sources;

third current means for supplying a third current and in communication with the commonly connected first sources to form the first output terminal; and

fourth current means for supplying a third current and in communication with the commonly connected second sources to form the second output terminal.

25. (Currently Amended) The temperature and process independent analog integrated circuit of claim 22, wherein the first and second loading means comprise MOS transistors.

26. (Currently Amended) The temperature and process independent analog integrated circuit of claim 22, wherein [said] the compensation means comprises:

a first MOS transistor having

_____a first source in communication with the common mode voltage,

_____a first drain, and

_____ a first gate; and

first differential amplifier means for differentially amplifying a first bias voltage source and a signal from the first drain, wherein an output of the first differential amplifier means and a signal from the first gate form the compensation control signal.

27. (Currently Amended) The temperature and process independent analog integrated circuit of claim 26, wherein [said] the compensation means further comprises:

a second MOS transistor having

_____ a second gate,

_____ a second drain in communication with the first drain,
and

_____ a second source;

a third MOS transistor in communication with a second bias voltage source, the third MOS transistor having

_____ a third source in communication with a reference point, and

_____ a third drain in communication with the second source;
and

second differential amplifier means for amplifying as a first input the third drain and the second source, and as a

second input a third bias voltage source, and to provide output to the second gate.

28. (Currently Amended) The temperature and process independent analog integrated circuit of claim 27, wherein the first MOS transistor and the first and second loading devices are of [the] a first conductivity type, and the second and third MOS transistors are of [the] a second conductivity type.

29. (Currently Amended) The temperature and process independent analog integrated circuit of claim 22, further comprising biasing means to provide the common mode voltage to the first and second loading means.

30. (Currently Amended) The temperature and process independent analog integrated circuit of claim 27, further comprising a biasing circuit, wherein the biasing circuit [comprising] comprises:

means for generating the common mode voltage that is referenced to a semiconductor bandgap voltage;

means for providing a first bias voltage that is referenced to the semiconductor bandgap voltage;

means for providing a second bias voltage that is referenced to [a] the semiconductor bandgap voltage; and

means for providing a third bias voltage that is referenced to [a] the semiconductor _bandgap voltage.

31. (Currently Amended) The temperature and process independent analog integrated circuit of claim 29, wherein the common mode voltage is substantially proportional to a semiconductor bandgap voltage.

32. (Currently Amended) A temperature and process independent analog multiplier circuit comprising:

multiplier means for multiplying a first differential input signal pair and a second differential input signal pair to provide a first output signal and a second output [signals] signal;

first loading means for providing an output voltage in response to the first output signal, a common mode voltage signal, and a compensation control signal;

second loading means for providing an output voltage in response to the second output signal, the common mode voltage signal, and the compensation control signal; and

compensation [circuit] means for generating the compensation control signal to compensate for changes due to temperature and manufacturing variations.

33. (Currently Amended) The temperature and process independent analog multiplier circuit of claim 32, wherein the multiplier means comprises:

first current means for supplying a first current;

_____second current means for supplying a second current;

a first pair of first and second MOS transistors arranged in parallel, the first pair of first and second MOS transistors having

_____a gate of the first MOS transistor in communication with a first terminal of the first differential input signal pair,

_____a gate of the second MOS transistor in communication with a second terminal of the first differential input signal pair,

_____commonly connected first drains responsive to the first current, and

_____commonly connected first sources;

a second pair of third and fourth MOS transistors arranged in parallel, the second pair of third and fourth MOS transistors having

_____a gate of the third MOS transistor in communication with a first terminal of the second differential input signal pair,

_____ a gate of the fourth MOS transistor in communication with a second terminal of the second differential input signal pair,

_____ commonly connected second drains responsive to the second current, and

_____ commonly connected second sources;

third current means for supplying a third current and in communication with the commonly connected first sources to form the first output terminal; and

fourth current means for supplying a third current and in communication with the commonly connected second sources to form the second output terminal.

34. (Original) The temperature and process independent analog multiplier circuit of claim 32 wherein the first and second loading devices comprises MOS transistors.

35. (Currently Amended) The temperature and process independent analog multiplier circuit of claim 32, wherein [said] the compensation means comprises:

a first MOS transistor having

_____ a first source in communication with the common mode voltage,

_____ a first drain, and

_____ a first gate; and

first differential amplifier means for differentially amplifying a first bias voltage source and a signal from the first drain[,] and having an output, wherein the output of the first differential amplifier means and a signal from the first gate form the compensation control signal.

36. (Currently Amended) The temperature and process independent analog multiplier circuit of claim 35, wherein [said] the compensation means further comprises:

a second MOS transistor having

_____ a second gate,

_____ a second drain in communication with the first drain,
and

_____ a second source;

a third MOS transistor in communication with a second bias voltage source, the third MOS transistor having

_____ a third source in communication with a reference point, and

_____ a third drain in communication with the second source;
and

a second differential amplifier means for amplifying as a first input the third drain and the second source, and as a

second input a third bias voltage source, and to provide output to the second gate.

37. (Currently Amended) The temperature and process independent analog multiplier circuit of claim [32] 35, wherein the first MOS transistor and the first and second loading devices are of [the] a first conductivity type, and the second and third MOS transistors are of [the] a second conductivity type.

38. (Currently Amended) The temperature and process independent analog multiplier circuit of claim 35, further comprising biasing means for providing a common mode voltage to the first and second loading means.

39. (Currently Amended) The temperature and process independent analog multiplier circuit of claim 37, further comprising biasing means, wherein the biasing means [comprising] comprises:

means to generate the common mode voltage, the common mode voltage being [that is] referenced to a semiconductor bandgap voltage;

means for providing a first bias voltage, the first bias voltage being [that is] referenced to the semiconductor bandgap voltage;

means for providing a second bias voltage, the second bias voltage being [that is] referenced to [a] the semiconductor bandgap voltage; and

means for providing a third bias voltage that is referenced to [a] the semiconductor bandgap voltage.

40. (Currently Amended) The temperature and process independent analog [integrated] multiplier circuit of claim 38, wherein the common mode voltage is substantially proportional to a semiconductor bandgap voltage.

41. (Currently Amended) A temperature and process compensation circuit in communication with control terminals of an active load of an analog integrated circuit to counteract changes in an output level of said analog integrated circuit due to temperature and manufacturing process, [said] the temperature and process compensation circuit comprising:

a first MOS transistor having
_____ a first source in communication with a common mode voltage,
_____ a first drain, and

_____ a first gate; and

first differential amplifier means for differentially amplifying a first bias voltage source and a signal from the first drain, and an output, wherein the output of the first differential amplifier means and a signal from the first gate form a compensation control signal;

a second MOS transistor having

_____ a second gate,

_____ a second drain in communication with the first drain,
and

_____ a second source;

a third MOS transistor in communication with a second bias voltage source, the third MOS transistor having

_____ a third source in communication with a reference point, and

_____ a third drain in communication with the second source;
and

a second differential amplifier means for amplifying as a first input the third drain and the second source, and as a second input a third bias voltage source, and to provide output to the second gate.

42. (Currently Amended) The temperature and process compensation circuit of claim 41, wherein the first MOS

transistor is of [the] a first conductivity type, and the second and third MOS transistors are of [the] a second conductivity type.

43. (Currently Amended) The temperature and process compensation circuit of claim 41, further comprising biasing means to provide the common mode voltage and to provide the first bias voltage source, second bias voltage source, and third bias voltage source to said temperature and process compensation circuit.

44. (Currently Amended) The temperature and process compensation circuit of claim 43, wherein said biasing means comprises:

means to generate the common mode voltage, the common mode voltage being [that is] referenced to a semiconductor bandgap voltage;

means to generate a first bias voltage, the first bias voltage being [that is] referenced to the semiconductor bandgap voltage;

means to generate the second bias voltage [circuit], the second bias voltage being [that is] referenced to the semiconductor bandgap voltage; and

means to generate the third bias voltage, the third bias voltage being [that is] referenced to the semiconductor bandgap voltage.

45. (Previously Presented) An integrated circuit, comprising:

an analog function circuit;

a differential loading device in communication with a differential output of the analog function circuit;

a compensation circuit in communication with the differential loading device; and

a biasing circuit in communication with a common mode node of the differential loading device and an input of the compensation circuit,

wherein the biasing circuit provides a common mode voltage to the common mode node of the differential loading device and the compensation circuit, and

wherein the common mode voltage is independent of temperature and manufacturing process variations, and

wherein the biasing circuit provides a plurality of control bias voltage signals to the compensation circuit.

Claim 46 is cancelled.

47. (Previously Presented) The integrated circuit of claim 45, wherein the compensation circuit provides a bias voltage to the differential loading device, and wherein the bias voltage is independent of temperature and manufacturing process variations.

48. (Previously Presented) The integrated circuit of claim 47, wherein the bias voltage varies a differential loading of the differential loading device.

49. (Previously Presented) The integrated circuit of claim 47, wherein the bias voltage is comprised of at least the common mode voltage and the plurality of control bias voltage signals.

50. (Previously Presented) The integrated circuit of claim 47, wherein the bias voltage controls a loading on at least one voltage signal associated with the differential loading device.

51. (Previously Presented) The integrated circuit of claim 47, wherein the differential loading device provides the temperature and process independent output voltage comprised of

at least a differential output signal of the analog function circuit, the common mode voltage, and the bias voltage.

52. (Previously Presented) The integrated circuit of claim 45, wherein the plurality of control bias voltage signals are substantially proportional to a semiconductor bandgap voltage.

53. (Previously Presented) The integrated circuit of claim 45, wherein the common mode voltage is substantially proportional to a semiconductor bandgap voltage.

54. (Previously Presented) The integrated circuit of claim 45, wherein the analog function circuit comprises a circuit selected from the group consisting of multipliers, adaptive filters, modulators and neural networks.

55. (Previously Presented) The integrated circuit of claim 45, wherein the differential loading device comprises first and second transistors,

wherein the first transistor comprises a first terminal responsive to a first output terminal of the analog function circuit, a second terminal in communication with the common mode node, and a first control terminal,

wherein the second transistor comprises a third terminal responsive to a second output terminal of the analog function circuit, a fourth terminal in communication with the common mode node, and a second control terminal, and

wherein the biasing circuit is in communication with the first and second control terminals.

56. (Previously Presented) An integrated circuit, comprising:

an analog function means for performing an analog function;

a differential loading means for providing a differential load,

wherein the differential loading means is in communication with a differential output of the analog function means;

a compensation means for providing a compensation signal,

wherein the compensation means is in communication with the differential loading means; and

a biasing means for providing a bias signal,

wherein the biasing means is in communication with a common mode node of the differential loading means and an input of the compensation means,

wherein the biasing means provides a common mode voltage to the common mode node of the differential loading means and the compensation means, and

wherein the common mode voltage is independent of temperature and manufacturing process variations, and

wherein the biasing means comprises means for generating a plurality of control bias voltage signals for the compensation means.

Claim 57 is cancelled.

58. (Previously Presented) The integrated circuit of claim 56, wherein the compensation means comprises means for generating a bias voltage for the differential loading means, and

wherein the bias voltage is independent of temperature and manufacturing process variations.

59. (Previously Presented) The integrated circuit of claim 58, wherein the bias voltage varies a differential loading of the differential loading means.

60. (Previously Presented) The integrated circuit of claim 58, wherein the bias voltage is comprised of at least the

common mode voltage and the plurality of control bias voltage signals.

61. (Previously Presented) The integrated circuit of claim 58, wherein the bias voltage controls a loading on at least one voltage signal associated with the differential loading means.

62. (Previously Presented) The integrated circuit of claim 58, wherein the differential loading means provides the temperature and process independent output voltage comprised of at least a differential output signal of the analog function means, the common mode voltage, and the bias voltage.

63. (Previously Presented) The integrated circuit of claim 58, wherein the plurality of control bias voltage signals are substantially proportional to a semiconductor bandgap voltage.

64. (Previously Presented) The integrated circuit of claim 56, wherein the common mode voltage is substantially proportional to a semiconductor bandgap voltage.

65. (Previously Presented) The integrated circuit of claim 56, wherein the analog function means comprises a circuit selected from the group consisting of multipliers, adaptive filters, modulators and neural networks.

66. (Previously Presented) The integrated circuit of claim 56, wherein the differential loading means comprises first and second loading means,

wherein the first loading means comprises a first terminal responsive to a first output terminal of the analog function means, a second terminal in communication with the common mode node, and a first control terminal,

wherein the second loading means comprises a third terminal responsive to a second output terminal of the analog function means, a fourth terminal in communication with the common mode node, and a second control terminal, and

wherein the biasing means is in communication with the first and second control terminals.

67. (Previously Presented) A method of performing an analog function, comprising the steps of:

- a.) differentially loading the analog function;
- b.) providing a common mode node to step (a.);
- c.) providing a compensation signal to step (a.);

d.) providing a common mode voltage to step (a.) via the common mode node, wherein the common mode voltage is independent of temperature and manufacturing process variations; and

e.) providing the common mode voltage and a plurality of control bias voltage signals to step (c.).

68. (Previously Presented) The method of claim 67, wherein step (c.) further comprises the step of

f.) providing a bias voltage to step (a.),
wherein the bias voltage is independent of temperature and manufacturing process variations.

Claim 69 is cancelled.

70. (Previously Presented) The method of claim 67, wherein the compensation signal provided by step (c.) varies the differential loading of step (a.).

71. (Previously Presented) The method of claim 67, wherein the plurality of control bias voltage signals are substantially proportional to a semiconductor bandgap voltage.

72. (Previously Presented) The method of claim 67,
wherein the common mode voltage is substantially proportional to
a semiconductor bandgap voltage.